NSN 5961-01-400-1514

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View Online at https://aerobasegroup.com/nsn/5961-01-400-1514 **Inclosure Material:** Plastic and metal **Overall Length:** 0.865 inches **Mounting Method:** Terminal Semiconductor Material: ic:

| John John Garden Materian |
|---|
| Silicon |
| Voltage Rating In Volts Per Characteristi |
| 20.0 gate to source voltage |
| Special Features: |
| Repetitive avalanche field effect n-channel |
| Terminal Type And Quantity: |
| 3 uninsulated wire lead |
| Departure From Cited Designator: |
| Modified leads bent 3xr |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
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